

GT50J122

Current Resonance Inverter Switching Application

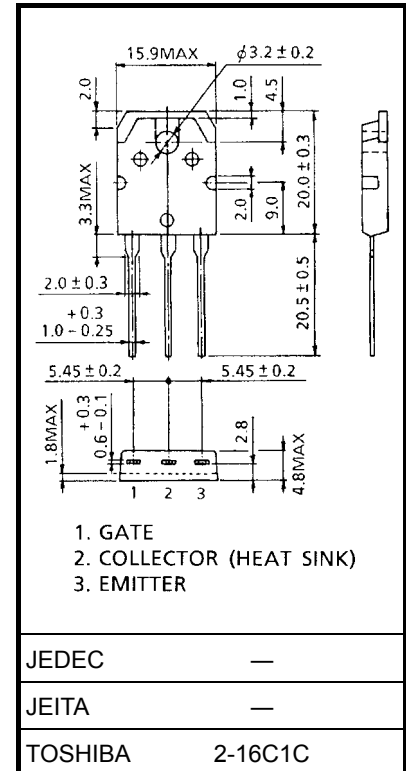
- Enhancement mode type
- High speed : $t_f = 0.16 \mu s$ (typ.) ($I_C = 60A$)
- Low saturation voltage: $V_{CE(sat)} = 1.9 V$ (typ.) ($I_C = 60A$)
- Fourth-generation IGBT
- TO-3P(N) (Toshiba package name)

Absolute Maximum Ratings ($T_a = 25^\circ C$)

Characteristics	Symbol	Rating	Unit
Collector-emitter voltage	V_{CES}	600	V
Gate-emitter voltage	V_{GES}	± 25	V
Continuous collector current	@ $T_c = 100^\circ C$	31	A
	@ $T_c = 25^\circ C$	50	
Pulsed collector current	I_{CP}	120	A
Collector power dissipation	@ $T_c = 100^\circ C$	62	W
	@ $T_c = 25^\circ C$	156	
Junction temperature	T_j	150	$^\circ C$
Storage temperature range	T_{stg}	-55 to 150	$^\circ C$

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Unit: mm

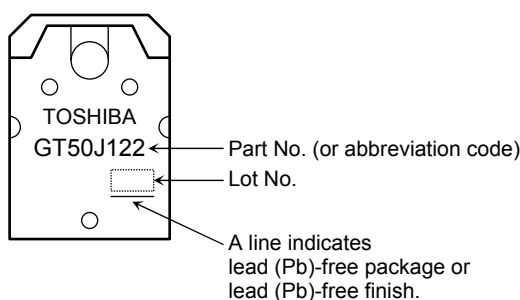


Weight: 4.6 g (typ.)

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance	$R_{th(j-c)}$	0.80	$^\circ C/W$

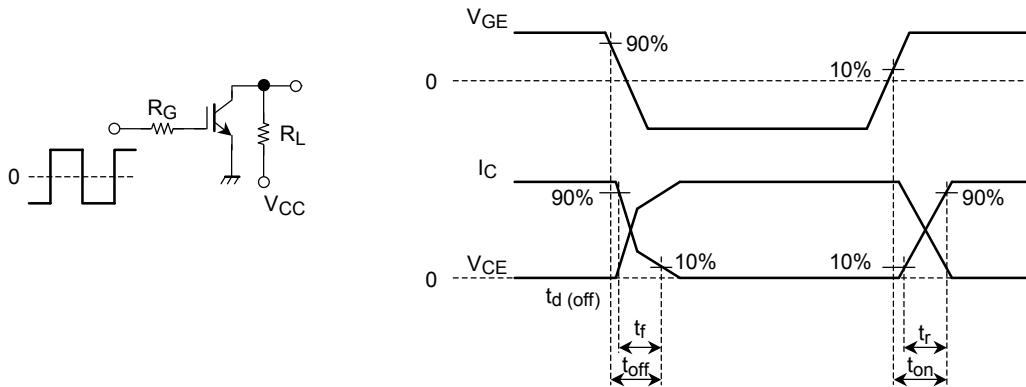
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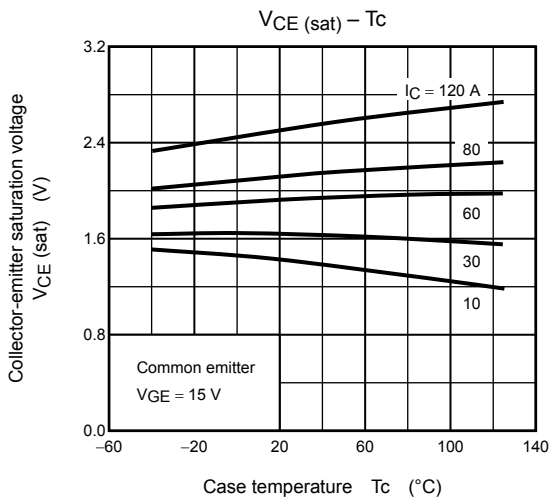
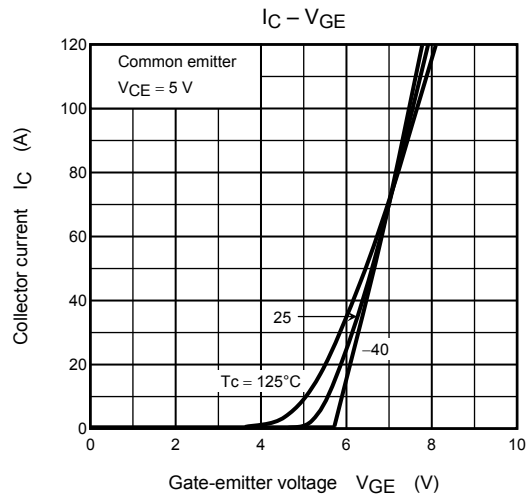
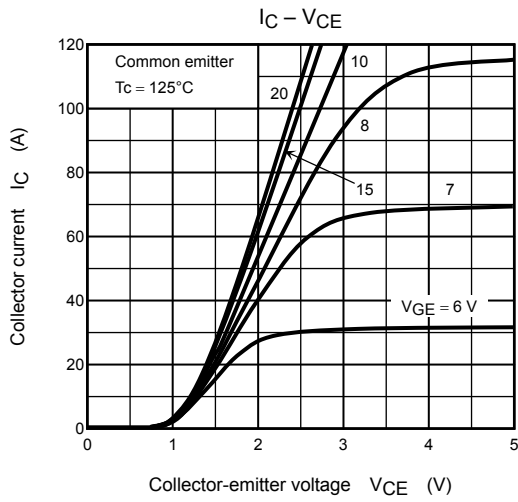
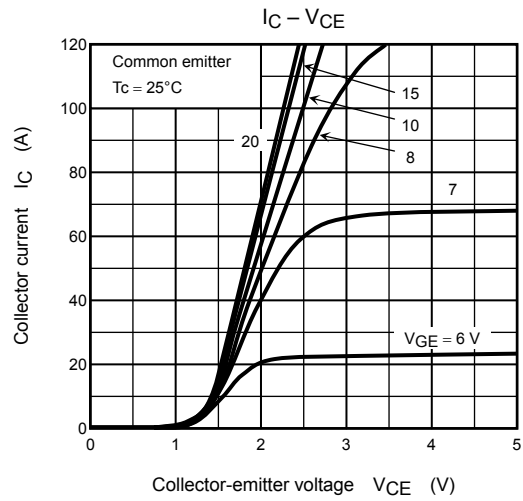
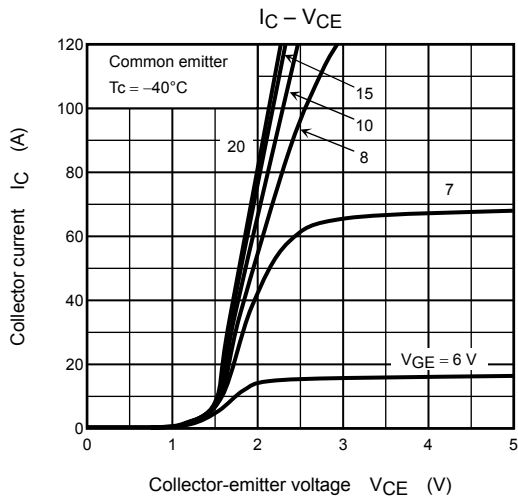


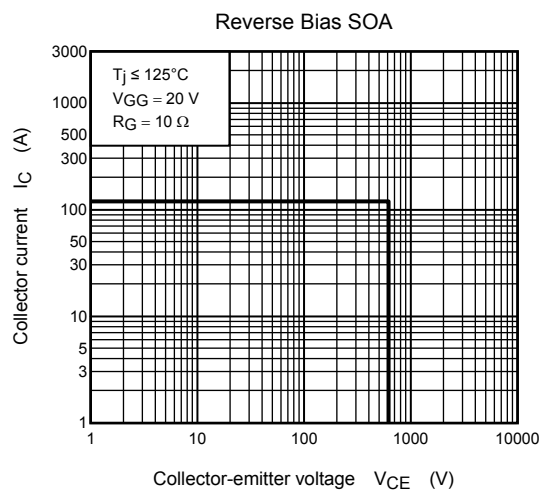
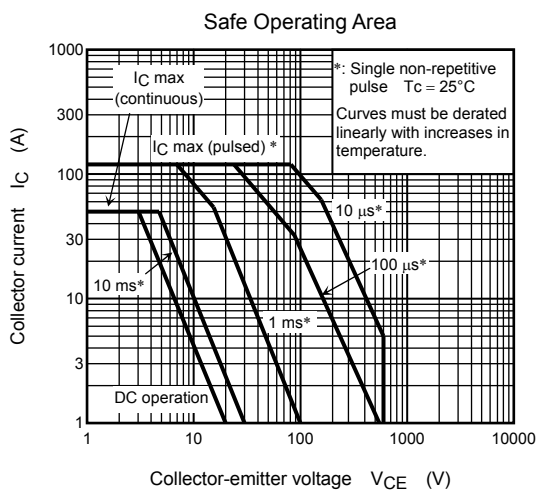
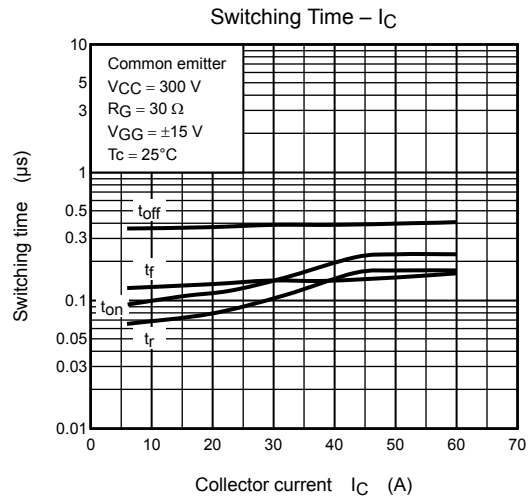
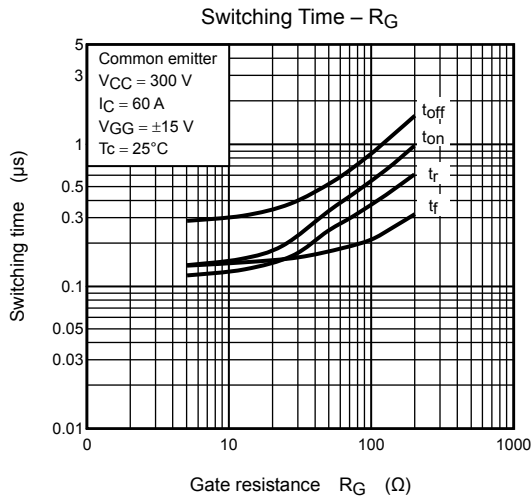
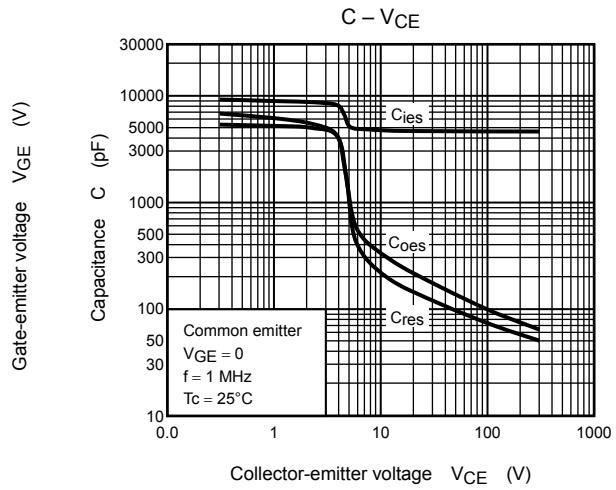
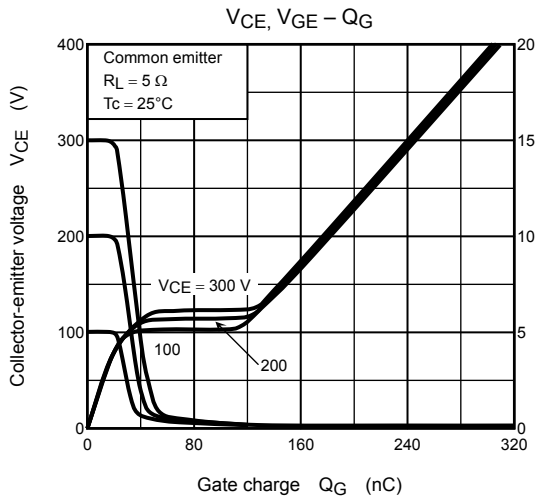
Electrical Characteristics (Ta = 25°C)

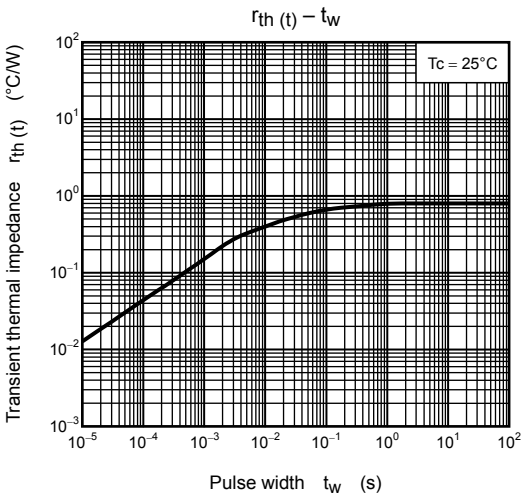
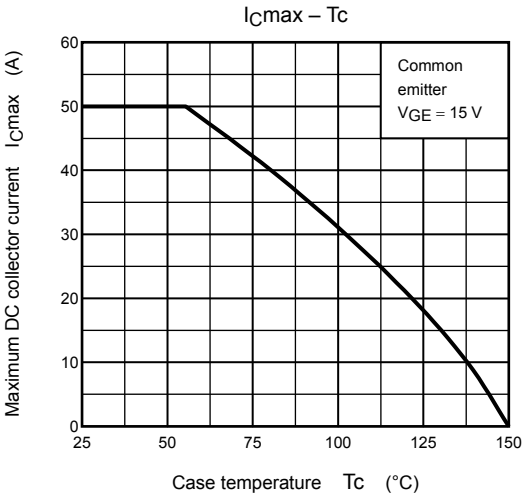
Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GES}	$V_{GE} = \pm 25\text{ V}, V_{CE} = 0$	—	—	± 500	nA
Collector cut-off current		I_{CES}	$V_{CE} = 600\text{ V}, V_{GE} = 0$	—	—	1.0	mA
Gate-emitter cut-off voltage		$V_{GE(OFF)}$	$I_C = 60\text{ mA}, V_{CE} = 5\text{ V}$	3.0	—	6.0	V
Collector-emitter saturation voltage		$V_{CE(sat)}$	$I_C = 60\text{ A}, V_{GE} = 15\text{ V}$	—	1.9	2.5	V
Input capacitance		C_{ies}	$V_{CE} = 10\text{ V}, V_{GE} = 0, f = 1\text{ MHz}$	—	4800	—	pF
Switching time	Rise time	t_r	Resistive Load $V_{CC} = 300\text{ V}, I_C = 60\text{ A}$ $V_{GG} = \pm 15\text{ V}, R_G = 30\ \Omega$ (Note 1)	—	0.17	—	μs
	Turn-on time	t_{on}		—	0.23	—	
	Fall time	t_f		—	0.16	0.26	
	Turn-off time	t_{off}		—	0.41	—	

Note 1: Switching time measurement circuit and input/output waveforms









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